

FG/CTL amplifier

BA6305/BA6305F

The BA6305 and BA6305F are fast-response wave-shaping preamplifiers for use in VCR CTL amplifiers. They meet the fast REC mode to PB mode response required in VCR CTL amplifiers. The ICs contain a fast-response preamplifier (with precharge function) and a noise-rejecting hysteresis amplifier that converts the CTL signal to a rectangular-wave output. The hysteresis width can be switched between two levels to maintain the S/N ratio, and provide compatibility with various tape speeds.

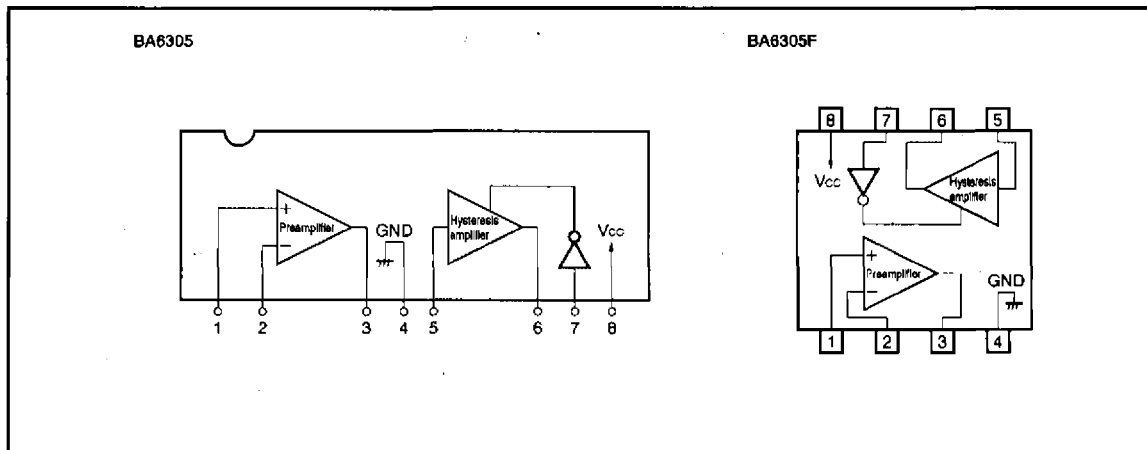
●Applications

- VCR CTL amplifiers
- VCR FG amplifiers
- VCR DTP amplifiers
- Other preamplifier and hysteresis amplifier applications

●Features

- 1)Fast response from strong input when recording to CTL signal playback when playing.
- 2)High gain.
- 3)Schmitt trigger circuit ensures high S/N ratio, and accurate hysteresis width and level.
- 4)The hysteresis comparator level can be switched to suit the CTL amplifier level.
- 5)Compact SIP 8 pin and SOP 8pin packages.

●Block diagram



● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Power supply voltage	V _{CC}	15	V
Power dissipation	P _d	400*	mW
Operating temperature	T _{opr}	-20~70	°C
Storage temperature	T _{stg}	-55~125	°C

* Reduced by 4.0mW for each increase in Ta of 1°C over 25°C.

● Electrical characteristics (Unless otherwise specified Ta=25°C and V_{CC}=9V)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Operating voltage	V _{CC}	4.5	—	13.0	V	—
Quiescent current	I _Q	0.6	1.5	2.6	mA	—
Preampifier bias voltage	V _{B<pre></pre>}	1.0	1.3	1.6	V	—
Small-signal preampifier input resistance	R _{INS}	20	30	40	kΩ	V _{IN} =1.0V
Large-signal preampifier input resistance	R _{EN}	2.1	4.4	9.0	kΩ	V _{IN} =5.0V
Preampifier bias input current	I _{B<pre></pre>}	—	30	300	nA	—
Preampifier output level	V _{O<pre></pre>}	2.0	2.4	—	V _{p-p}	—
Preampifier open-loop voltage gain	G _{VO}	64.0	72.5	—	dB	R _{NF} =330kΩ
Preampifier input conversion noise voltage	V _{N<pre></pre>}	—	3.4	12.0	μV _{rms}	DIN Audio R _g =2.2kΩ
Schmitt circuit input bias potential	V _{B<hys< sub=""></hys<>}	1.6	2.0	2.4	V	—
Schmitt circuit hysteresis width I	V _{hys I}	±70	±90	±130	mV _{O-P}	—
Schmitt circuit hysteresis width II	V _{hys II}	±200	±250	±360	mV _{O-P}	—
Schmitt circuit output level	V _{ohys}	5.1	6.6	—	V _{p-p}	R _L =20kΩ

The switching time from REC mode to PB mode is 1 sec. (Max.), and the power on start up time is 3 sec. (Max.).

● External dimensions (Units: mm)

